

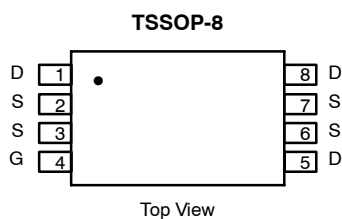
N-Channel 2.5-V (G-S) MOSFET

PRODUCT SUMMARY

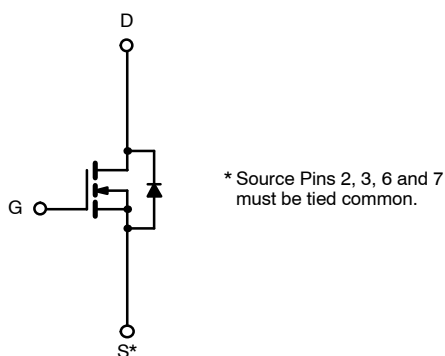
V_{DS} (V)	$r_{DS(on)}$ (Ω)	I_D (A)
20	0.014 @ $V_{GS} = 4.5$ V	7.8
	0.021 @ $V_{GS} = 2.5$ V	6.3

FEATURES

- TrenchFET® Power MOSFET
- 100% R_g Tested



Ordering Information: Si6466DQ-T1



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V_{DS}	20	V
Gate-Source Voltage		V_{GS}	± 12	
Continuous Drain Current ($T_J = 150^\circ\text{C}$) ^a	$T_A = 25^\circ\text{C}$	I_D	7.8	A
	$T_A = 70^\circ\text{C}$		6.2	
Pulsed Drain Current		I_{DM}	30	
Continuous Source Current (Diode Conduction) ^a		I_S	1.50	
Maximum Power Dissipation ^a	$T_A = 25^\circ\text{C}$	P_D	1.5	W
	$T_A = 70^\circ\text{C}$		1.0	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	-55 to 150	$^\circ\text{C}$

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Limit	Unit
Maximum Junction-to-Ambient ^a	R_{thJA}	83	$^\circ\text{C/W}$

Notes

a. Surface Mounted on FR4 Board, $t \leq 10$ sec.

For SPICE model information via the Worldwide Web: <http://www.vishay.com/www/product/spice.htm>

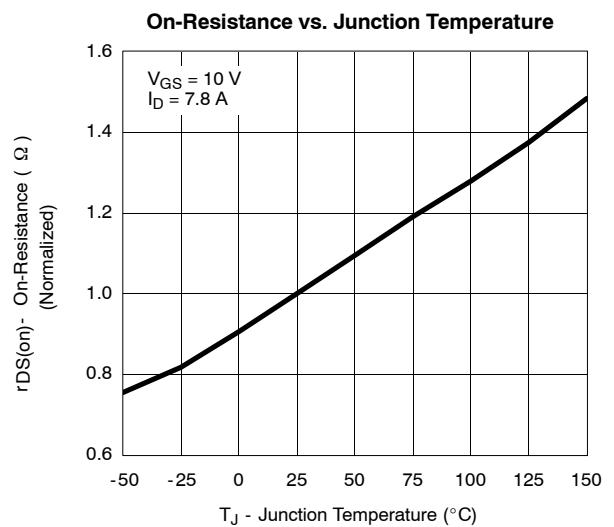
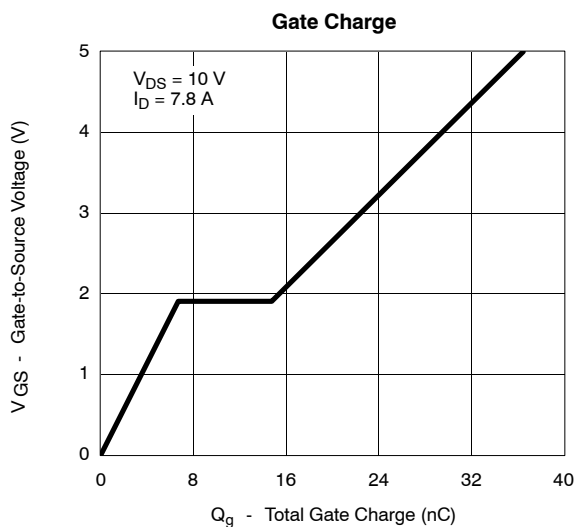
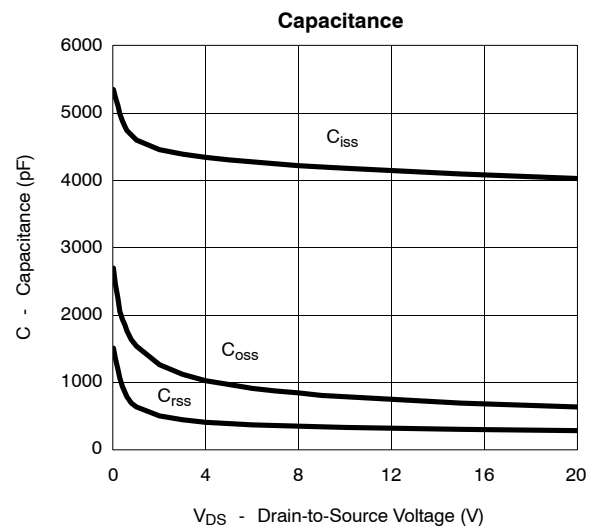
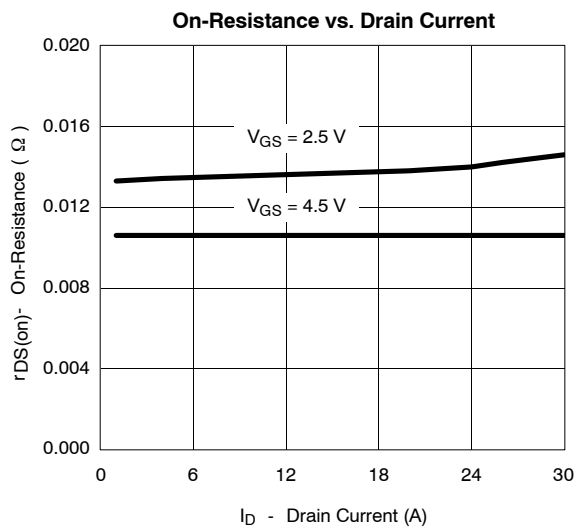
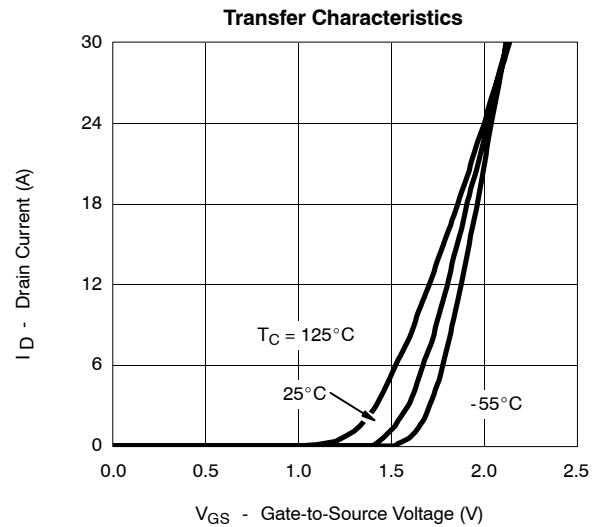
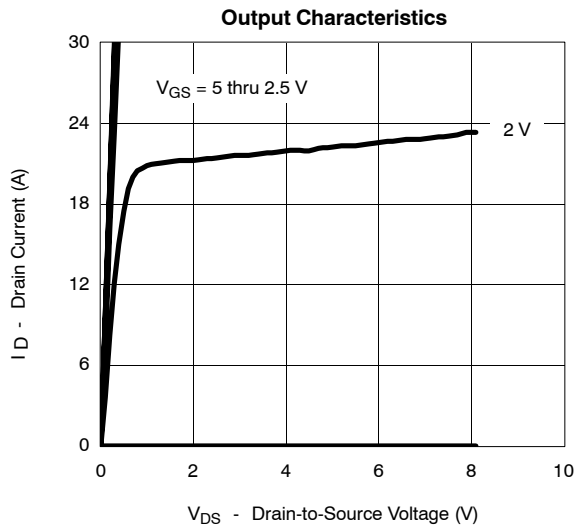
SPECIFICATIONS ($T_J = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)						
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Static						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 250\ \mu\text{A}$	0.6			V
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0\ \text{V}$, $V_{GS} = \pm 12\ \text{V}$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 20\ \text{V}$, $V_{GS} = 0\ \text{V}$			1	μA
		$V_{DS} = 20\ \text{V}$, $V_{GS} = 0\ \text{V}$, $T_J = 55^\circ\text{C}$			25	
On-State Drain Current ^a	$I_{D(on)}$	$V_{DS} = 5\ \text{V}$, $V_{GS} = 10\ \text{V}$	20			A
Drain-Source On-State Resistance ^a	$r_{DS(on)}$	$V_{GS} = 4.5\ \text{V}$, $I_D = 7.8\ \text{A}$		0.0105	0.014	Ω
		$V_{GS} = 2.5\ \text{V}$, $I_D = 6.3\ \text{A}$		0.0135	0.021	
Forward Transconductance ^a	g_{fs}	$V_{DS} = 10\ \text{V}$, $I_D = 7.8\ \text{A}$		45		S
Diode Forward Voltage ^a	V_{SD}	$I_S = 1.50\ \text{A}$, $V_{GS} = 0\ \text{V}$		0.7	1.1	V
Dynamic^b						
Total Gate Charge	Q_g	$V_{DS} = 10\ \text{V}$, $V_{GS} = 4.5\ \text{V}$, $I_D = 7.8\ \text{A}$		34	60	nC
Gate-Source Charge	Q_{gs}			6.7		
Gate-Drain Charge	Q_{gd}			8.1		
Gate Resistance	R_g		0.2		1.9	Ω
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 10\ \text{V}$, $R_L = 10\ \Omega$ $I_D \approx 1\ \text{A}$, $V_{GEN} = 10\ \text{V}$, $R_G = 6\ \Omega$		19	40	ns
Rise Time	t_r			30	60	
Turn-Off Delay Time	$t_{d(off)}$			130	250	
Fall Time	t_f			40	80	
Source-Drain Reverse Recovery Time	t_{rr}	$I_F = 1.50\ \text{A}$, $di/dt = 100\ \text{A}/\mu\text{s}$		50	80	

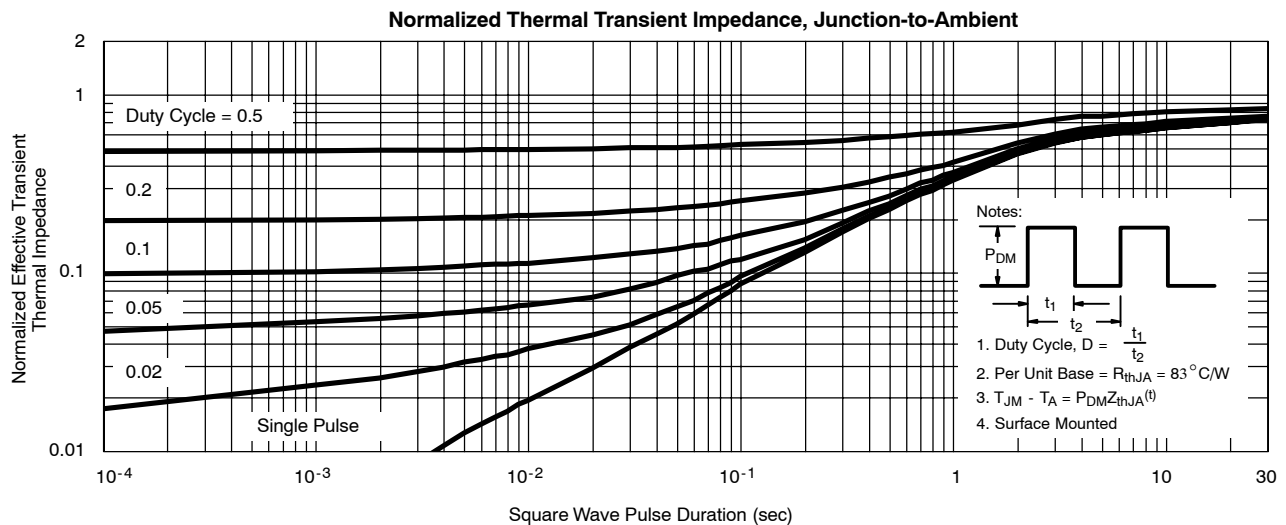
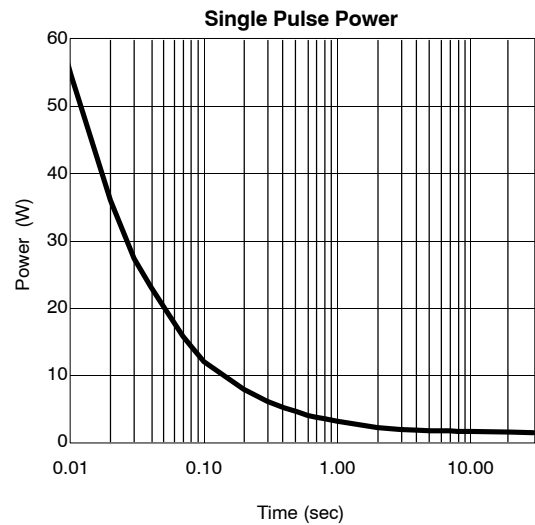
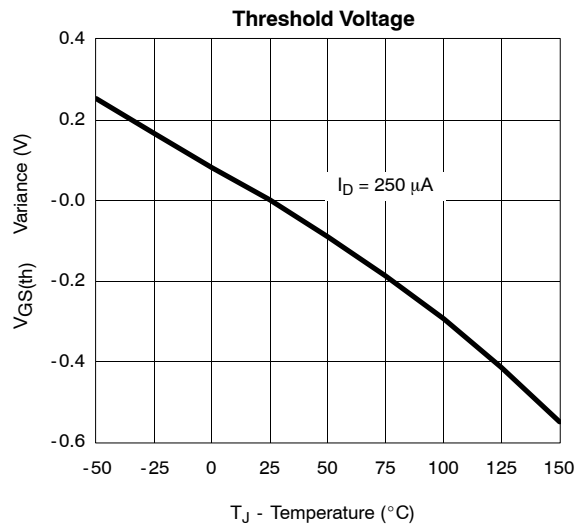
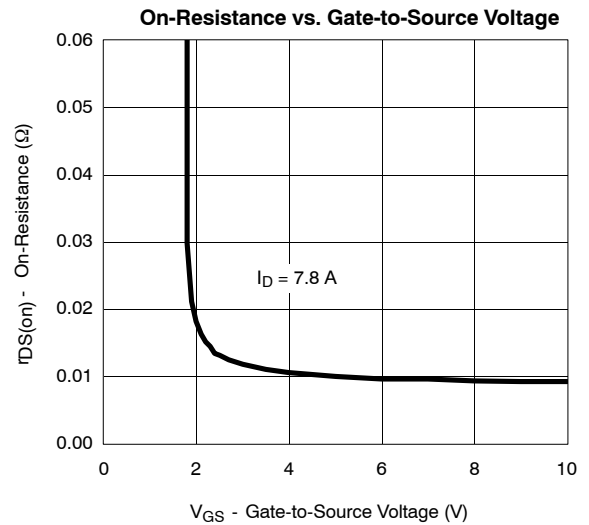
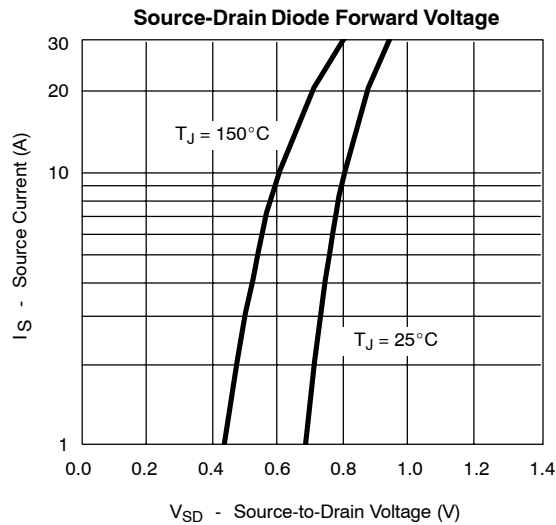
Notes

- a. Pulse test; pulse width $\leq 300\ \mu\text{s}$, duty cycle $\leq 2\%$.
b. Guaranteed by design, not subject to production testing.



TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)



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